

RJF0410JPE

40V - 40A - N Channel Thermal FET Power Switching

R07DS1237EJ0200 Rev.2.00 Jan 29, 2015

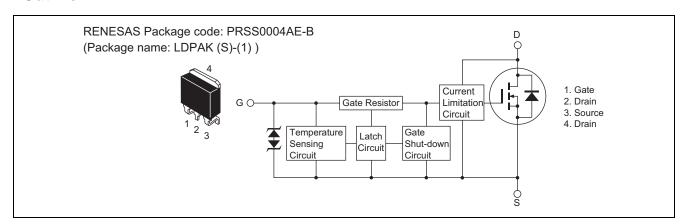
Description

This FET has the over temperature shut-down capability sensing to the junction temperature. This FET has the built-in over temperature shut-down circuit in the gate area. And this circuit operation to shut-down the gate voltage in case of high junction temperature like applying over power consumption, over current etc..

Features

- Logic level operation.
- Built-in the over temperature shut-down circuit.
- High endurance capability against to the short circuit.
- Latch type shut down operation (need 0 voltage recovery).
- Built-in the current limitation circuit.
- Power supply voltage applies 12 V.
- AEC-Q101 Compliant

Outline



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item	Symbol	Ratings	Unit
Drain to source voltage	V _{DSS}	40	V
Gate to source voltage	V_{GSS}	16	V
Gate to source voltage	V_{GSS}	-2.5	V
Drain current	I _D Note3	40	Α
Body-drain diode reverse drain current	I _{DR}	40	Α
Avalanche current	I _{AP} Note 2	12	Α
Avalanche energy	E _{AR} Note 2	960	mJ
Channel dissipation	Pch Note 1	100	W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Notes: 1. Value at $Tc = 25^{\circ}C$

- 2. Tch = 25°C, Rg \geq 50 Ω
- 3. It provides by the current limitation lower bound value.

Typical Operation Characteristics

 $(Ta = 25^{\circ}C)$

Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Input voltage	V _{IH}	3.5	_	_	V	
	V_{IL}	_	_	1.2	V	
Input current	I _{IH1}	1	_	100	μΑ	$Vi = 8 V$, $V_{DS} = 0$
(Gate non shut down)	I _{IH2}	1	_	50	μΑ	$Vi = 3.5 V, V_{DS} = 0$
	IιL	1	_	1	μΑ	Vi = 1.2 V, V _{DS} = 0
Input current	I _{IH(sd)1}	1	0.8	_	mA	$Vi = 8 V, V_{DS} = 0$
(Gate shut down)	I _{IH(sd)2}	1	0.35	_	mA	$Vi = 3.5 V, V_{DS} = 0$
Shut down temperature	Tsd	1	175	_	°C	Channel temperature
Gate operation voltage	Vop	3.5	_	12	V	
Drain current	I _{D limt}	40	_	_	Α	V _{GS} = 5 V, V _{DS} = 10 V Note 4
(Current limitation value)						

Notes: 4. Pulse test

Electrical Characteristics

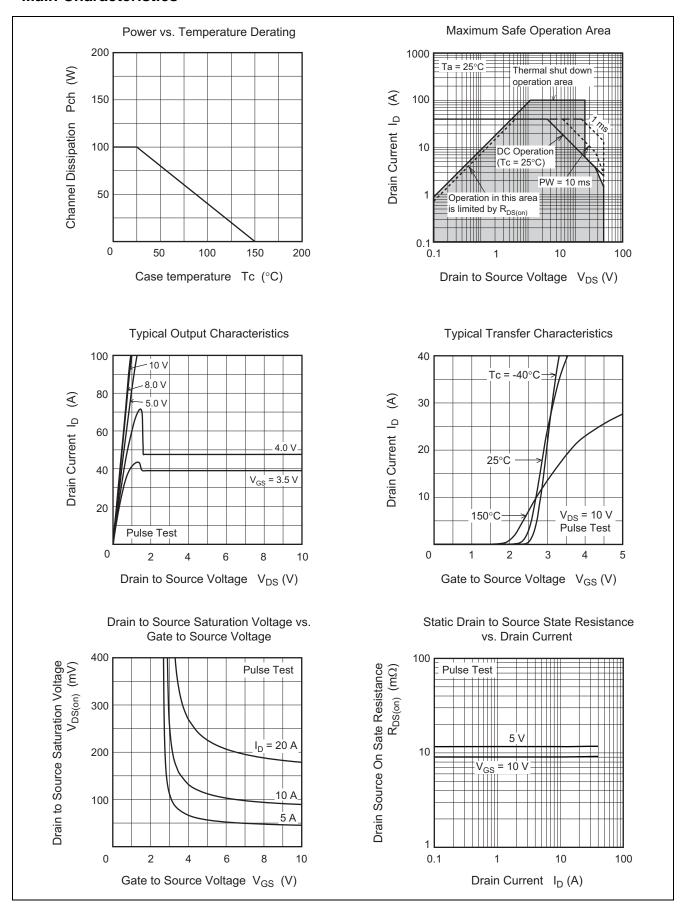
 $(Ta = 25^{\circ}C)$

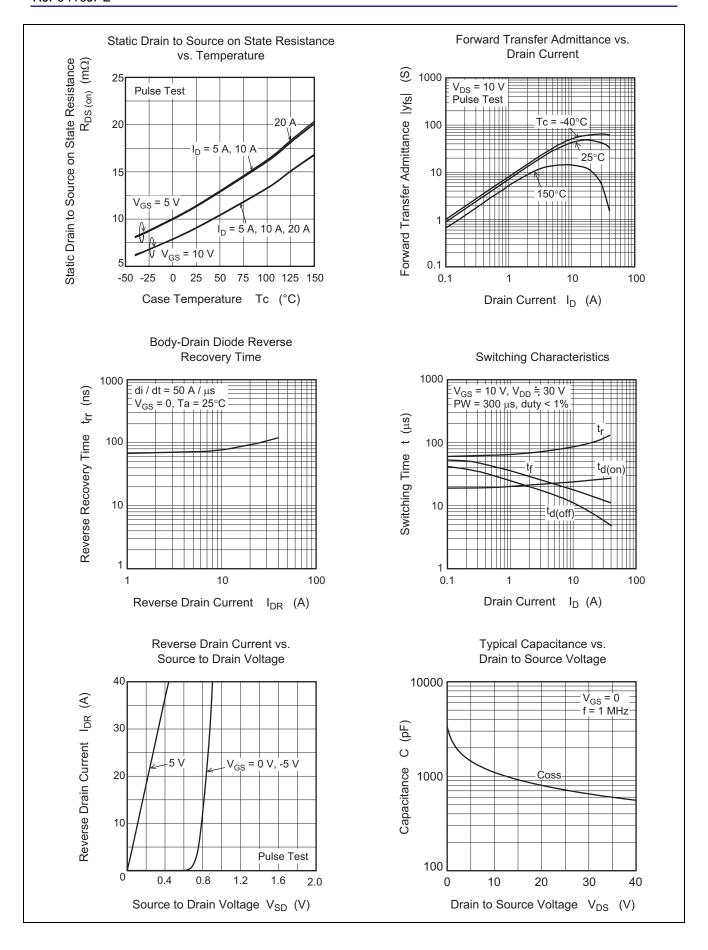
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain current	I _{D1}	_	_	60	Α	V _{GS} = 3.5 V, V _{DS} = 10 V Note 5
	I _{D2}	_	_	10	mA	V _{GS} = 1.2 V, V _{DS} = 10 V
	I _{D3}	40	_	_	Α	V _{GS} = 5 V, V _{DS} = 10 V Note 5
Drain to source breakdown voltage	V _{(BR)DSS}	40	_	_	V	$I_D = 10 \text{ mA}, V_{GS} = 0$
Gate to source breakdown	V _{(BR)GSS}	16	_	_	V	$I_G = 800 \mu A, V_{DS} = 0$
voltage	V _{(BR)GSS}	-2.5	_	_	V	$I_G = -100 \mu\text{A}, V_{DS} = 0$
Gate to source leak current	I _{GSS1}	_	_	100	μΑ	V _{GS} = 8 V, V _{DS} = 0
	I _{GSS2}	_	_	50	μΑ	V _{GS} = 3.5 V, V _{DS} = 0
	I _{GSS3}	_	_	1	μΑ	V _{GS} = 1.2 V, V _{DS} = 0
	I _{GSS4}	_	_	-100	μΑ	$V_{GS} = -2.4 \text{ V}, V_{DS} = 0$
Input current (shut down)	I _{GS(OP)1}	_	0.8	_	mA	V _{GS} = 8 V, V _{DS} = 0
	I _{GS(OP)2}	_	0.35	_	mA	V _{GS} = 3.5 V, V _{DS} = 0
Zero gate voltage drain current	I _{DSS}	_	_	10	μΑ	V _{DS} = 32 V, V _{GS} = 0, T _C = 110°C
Gate to source cutoff voltage	V _{GS(off)}	1.1	_	2.1	V	V _{DS} = 10 V, I _D = 1 mA
Forward transfer admittance	y _{fs}	20	46	_	S	I _D = 20 A, V _{DS} = 10 V Note 5
Static drain to source on state	R _{DS(on)}	_	11.3	15	mΩ	I _D = 20 A, V _{GS} = 5 V Note 5
resistance	R _{DS(on)}	_	9	13	mΩ	I _D = 20 A, V _{GS} = 10 V Note 5
Output capacitance	Coss	_	1098	_	pF	V _{DS} = 10 V, V _{GS} = 0, f = 1MHz
Turn-on delay time	t _{d(on)}	_	24.7	_	μs	$V_{GS} = 10 \text{ V}, I_{D} = 20 \text{ A}, R_{L} = 1.5 \Omega$
Rise time	tr	_	99.3	_	μs	
Turn-off delay time	t _{d(off)}	_	7.44	_	μs	
Fall time	tf	_	13.3	_	μs	
Body-drain diode forward voltage	V_{DF}	_	0.9	_	V	IF = 40 A, V _G S = 0 Note 5
Body-drain diode reverse recovery time	t _{rr}	_	122	_	ns	$I_F = 40 \text{ A}, V_{GS} = 0$ $di_F/dt = 50 \text{ A}/\mu\text{s}$
Over load shut down operation time Note 6	t _{os1}	_	0.63	_	ms	V _{GS} = 5 V, V _{DD} = 16 V

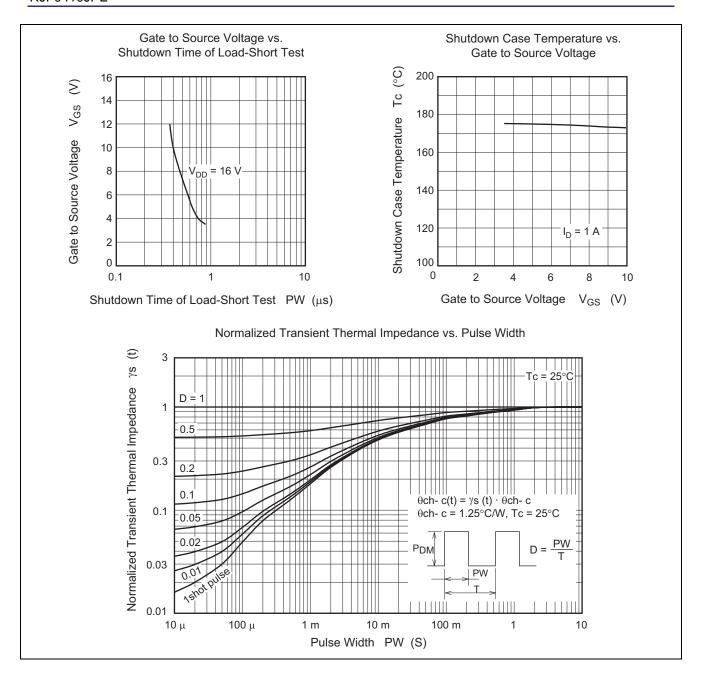
Notes: 5. Pulse test

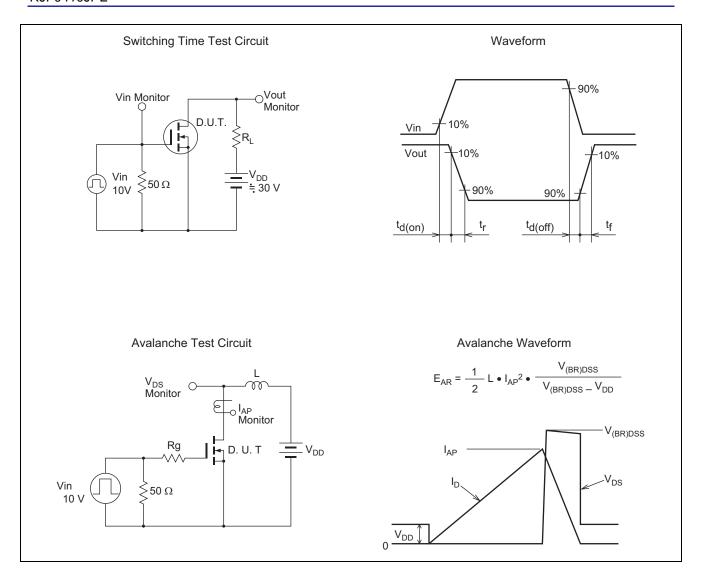
6. Including the junction temperature rise of the over loaded condition.

Main Characteristics

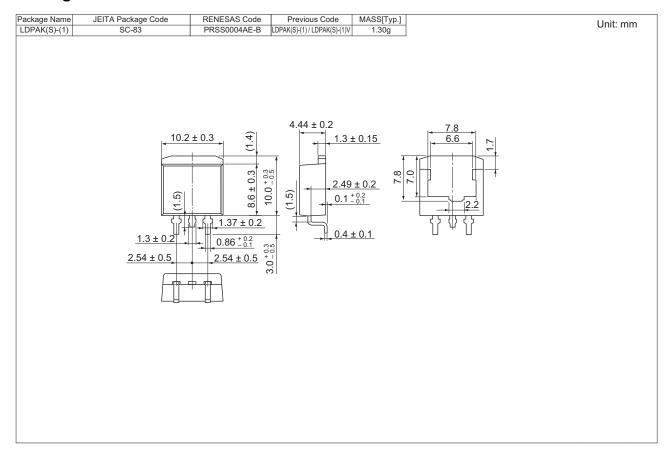








Package Dimensions



Ordering Information

Orderable Part Number	Quantity	Shipping Container
RJF0410JPE-00-J3	1000 pcs	Taping

Note: The symbol of 2nd "-" is occasionally presented as "#".

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